

Pin Description

Name	Pin #	Type	Description
GND	1, 9, 13	P	Connect to Ground
CLK_EN	2	I_PU	Synchronizing clock enable. When high, clock outputs follow clock input. When low, Qx outputs are forced low, nQx outputs are forced high. LVCMOS/LVTTL level with 80kΩ pull up.
CLK_SEL	3	I_PD	Clock select input. When high, selects CLK ₁ input. When low, selects CLK ₀ input. LVCMOS/LVTTL level with 80kΩ pull down.
CLK ₀	4	I_PD	LVCMOS / LVTTL clock input
CLK ₁	6	I_PD	LVCMOS / LVTTL clock input
NC	5, 7		No internal connection.
OE	8	I_PU	Output Enable. Controls outputs Q ₀ , nQ ₀ through Q ₃ , nQ ₃ .
V _{CC}	10, 18	P	Connect to 3.3V.
Q ₃ , nQ ₃	11, 12	O	Differential output pair, LVDS interface level.
Q ₂ , nQ ₂	14, 15	O	Differential output pair, LVDS interface level.
Q ₁ , nQ ₁	16, 17	O	Differential output pair, LVDS interface level.
Q ₀ , nQ ₀	19, 20	O	Differential output pair, LVDS interface level.

Notes:

1. I = Input, O = Output, P = Power supply connection, I_PD = Input with pull down, I_PU = Input with pull up.

Pin Characteristics

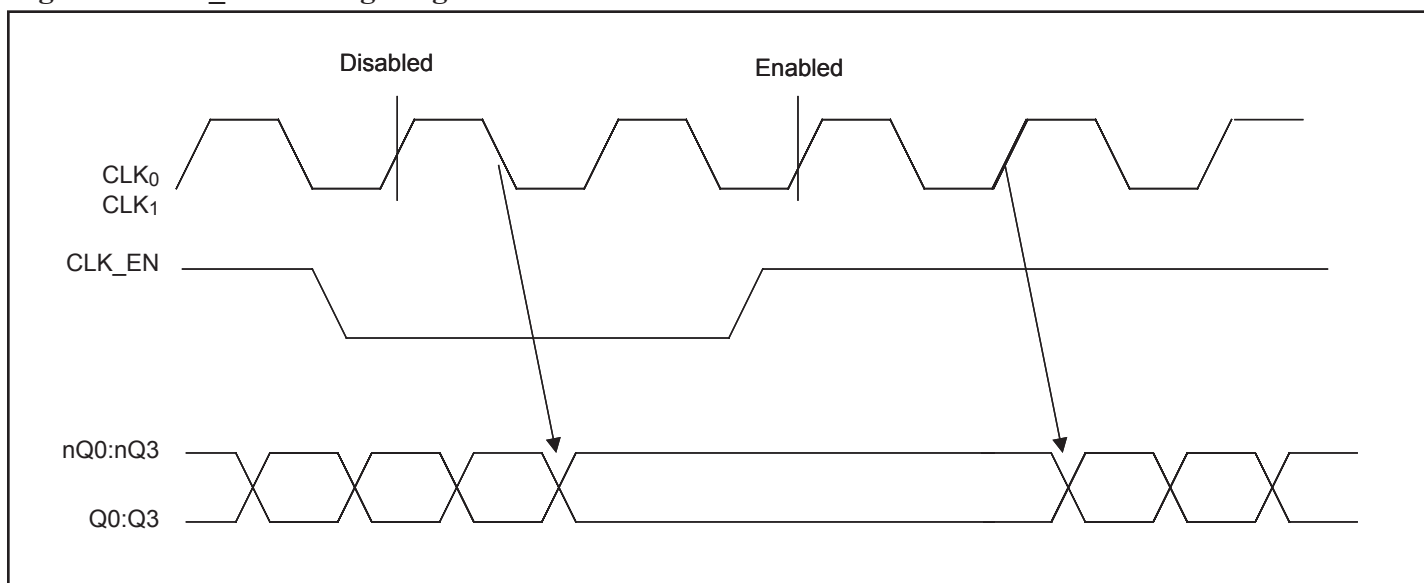
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
C _{IN}	Input Capacitance			6		pF
R _{pullup}	Input Pullup Resistance			80		kΩ
R _{pulldown}	Input Pulldown Resistance			80		

Control Input Function Table

Inputs				Outputs	
OE	CLK_EN	CLK_SEL	Selected Source	Q ₀ :Q ₃	nQ ₀ :nQ ₃
1	0	0	CLK ₀	Disabled: Low	Disabled: High
1	0	1	CLK ₁	Disabled: Low	Disabled: High
1	1	0	CLK ₀	Enabled	Enabled
1	1	1	CLK ₁	Enabled	Enabled
0	x	x		HiZ	HiZ

Notes:

1. After CLK_EN switches, the clock outputs are disabled or enabled following a rising and falling input clock edge as show below.

Figure 1. CLK_EN Timing Diagram

Clock Input Function Table

Inputs	Outputs	
CLK ₀ or CLK ₁	Q ₀ :Q ₃	nQ ₀ :nQ ₃
0	LOW	HIGH
1	HIGH	LOW

Absolute Maximum Ratings

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V _{CC}	Supply voltage	Referenced to GND			4.6	V
V _{IN}	Input voltage	Referenced to GND	-0.5		V _{CC} +0.5V	
V _{OUT}	Output voltage	Referenced to GND	-0.5		V _{CC} +0.5V	
T _{STG}	Storage temperature		-65		150	°C

Notes:

- Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only and correct functional operation of the device at these or any other conditions above those listed in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Operating Conditions

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V _{CC}	Power Supply Voltage		3.135	3.3	3.465	V
T _A	Ambient Temperature		-40		85	°C
I _{CC}	Power Supply Current				60	mA

LVC MOS/LVTTL DC Characteristics ($T_A = -40^{\circ}\text{C}$ to 85°C , $V_{CC} = 3.135\text{V}$ to 3.465V unless otherwise stated below.)

Symbol	Parameter		Conditions	Min.	Typ.	Max.	Units
V_{IH}	Input High Voltage	CLK ₀ , CLK ₁ , CLK_EN, CLK_SE, OE		2		$V_{CC}+0.3$	V
V_{IL}	Input Low Voltage	CLK ₀ , CLK ₁		-0.3		1.3	V
		CLK_EN, CLK_SEL, OE		-0.3		0.8	V
I_{IH}	Input High Current	CLK ₀ , CLK ₁ , CLK_SEL	$V_{IN} = V_{CC} = 3.465\text{V}$			150	uA
		CLK_EN, OE	$V_{IN} = V_{CC} = 3.465\text{V}$			5	uA
I_{IL}	Input Low Current	CLK ₀ , CLK ₁ , CLK_SEL	$V_{IN} = 0\text{V}$, $V_{CC} = 3.465\text{V}$	-5			uA
		CLK_EN, OE	$V_{IN} = 0\text{V}$, $V_{CC} = 3.465\text{V}$	-150			uA

LVDS DC Characteristics ($T_A = -40^{\circ}\text{C}$ to 85°C , $V_{CC} = 3.135\text{V}$ to 3.465V unless otherwise stated below.)

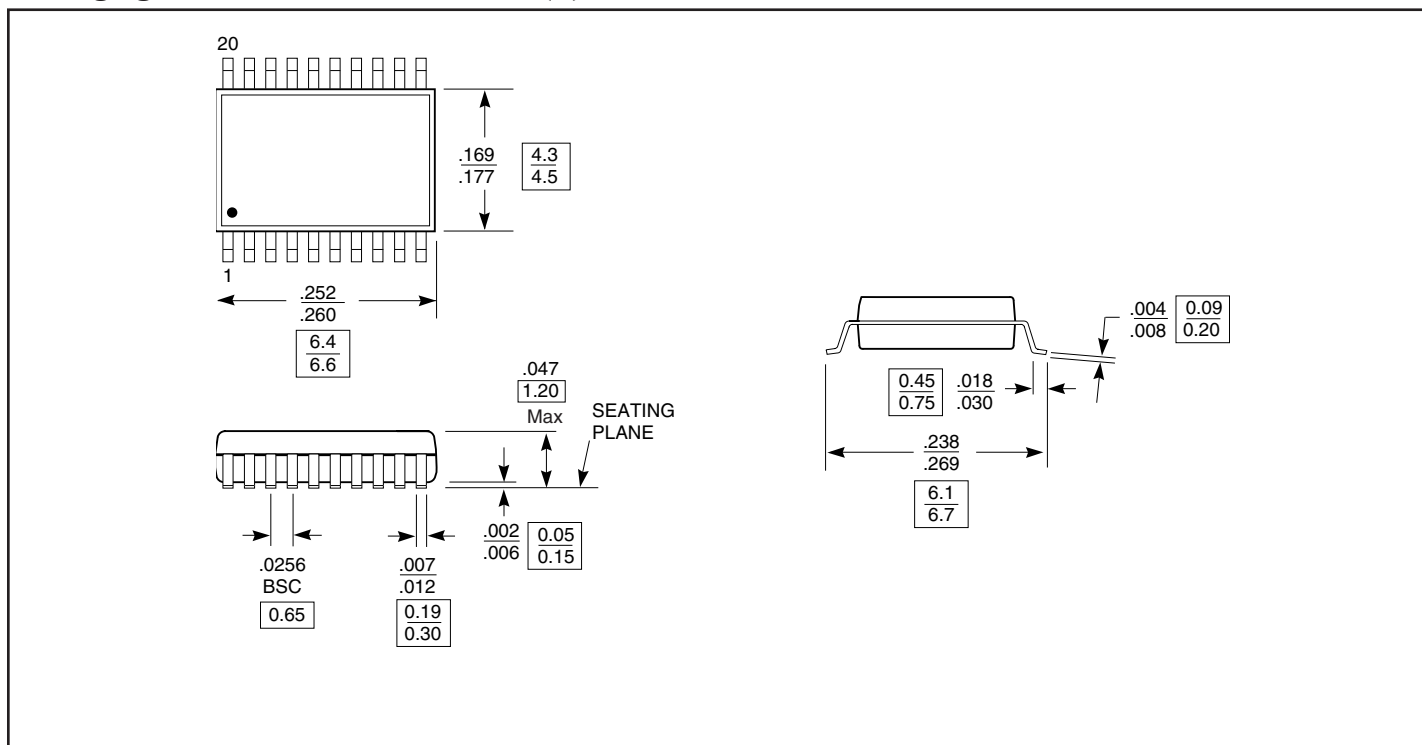
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{OD}	Differential Output Voltage		200	280	360	mV
ΔV_{OD}	V_{OD} Magnitude Change			0	40	
V_{OS}	Offset Voltage		1.125	1.3	1.475	V
ΔV_{OS}	V_{OS} Magnitude Change			5	25	mV
I_{OZ}	High Impedance Leakage Current		-10		+10	uA
I_{OFF}	Power OFF Leakage		-20	± 1	+20	
I_{OSD}	Differential Output Short Circuit Current			-3.5	-5	mA
I_{OS}	Output Short Circuit Current			-3.5	-5	
V_{OH}	Output Voltage High			1.34	1.6	V
V_{OL}	Output Voltage Low		0.9	1.06		

AC Characteristics ($T_A = -40^{\circ}\text{C}$ to 85°C , $V_{CC} = 3.135\text{V}$ to 3.465V)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
f_{max}	Output Frequency				650	MHz
t_{pd}	Propagation Delay ⁽¹⁾		0.8		2.2	ns
$T_{sk(o)}$	Output-to-output Skew ⁽²⁾				40	ps
$T_{sk(pp)}$	Part-to-part Skew ⁽³⁾				300	
t_r/t_f	Output Rise/Fall time	20% - 80%	100		300	
odc	Output duty cycle		48		52	%

Notes:

1. Measured from the $V_{CC}/2$ of the input to the differential output crossing point
2. Defined as skew between outputs at the same supply voltage and with equal load condition. Measured at the outputs differential crossing point.
3. Defined as skew between outputs on different parts operating at the same supply voltage and with equal load condition. Measured at the outputs differential crossing point.
4. All parameters are measured at 500MHz unless noted otherwise

Packaging Mechanical: 20-Pin TSSOP (L)

Ordering Information

Ordering Code	Package Code	Package Description
PI6C48545LE	L	Pb-free & Green 20-pin 173-mil wide TSSOP

Notes:

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- Number of Transistors = TBD